## NSN 5962-01-320-2539

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Body Length:
Between 11.23 millimeters and 11.68 millimeters
Body Width:
Between 11.23 millimeters and 11.68 millimeters
Body Height:
Between 1.52 millimeters and 2.54 millimeters
Maximum Power Dissipation Rating:
1.0 watts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
Features Provided:
Monolithic and ultraviolet erasable and programmable
Inclosure Material:
Ceramic
Inclosure Configuration:
Leadless flat pack
Output Logic Form:
Complementary-metal oxide-semiconductor logic
Input Circuit Pattern:
14 input
Case Outline Source And Designator:
C-4 mil-m-38510
Current Rating Per Characteristic:
120.00 milliamperes reverse current, dc absolute
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
-0.5 volts power source and 7.0 volts power source
Memory Device Type:
Eprom
Test Data Document:
96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).
Terminal Type And Quantity:
28 leadless
Shelf Life:
N/a
Unit Of Measure:

## Demilitarization:

Yes - demil/mli

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